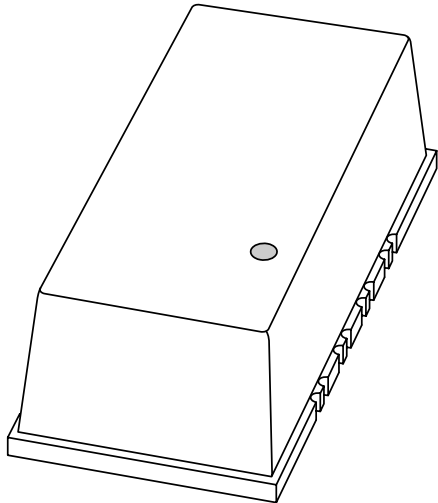


# DATA SHEET



## **BGS67A** 65 MHz, 25.5 dB gain reverse amplifier

Product specification  
Supersedes data of 2002 Jun 06

2002 Sep 06

# 65 MHz, 25.5 dB gain reverse amplifier

# BGS67A

### FEATURES

- Extremely low noise
- Excellent linearity
- Silicon nitride passivation
- Rugged construction
- Gold metallization ensures excellent reliability.

### APPLICATIONS

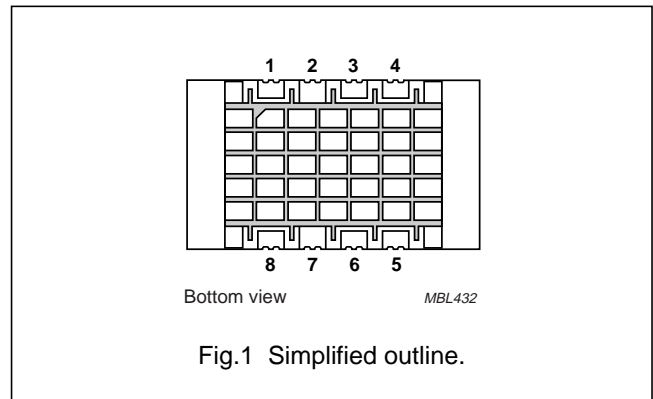
- Reverse amplifier in two-way CATV systems in the 5 to 65 MHz frequency range.

### DESCRIPTION

The BGS67A is a hybrid high dynamic range amplifier module in a leadless SOT567A package, operating at a supply voltage of 12 V.

### PINNING - SOT567A

PIN	DESCRIPTION
1	input
2	common
3	provision
4	+V <sub>B</sub>
5	output
6	provision
7	common
8	+V <sub>B</sub>



### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
G <sub>p</sub>	power gain	f = 10 MHz	25	26	dB
I <sub>tot</sub>	total current consumption (DC)	V <sub>B</sub> = 12 V	75	95	mA

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
V <sub>i</sub>	RF input voltage	-	55	dBmV
T <sub>stg</sub>	storage temperature	-40	+100	°C
T <sub>mb</sub>	operating mounting base temperature	-20	+100	°C

## 65 MHz, 25.5 dB gain reverse amplifier

BGS67A

**CHARACTERISTICS**Bandwidth 5 to 65 MHz;  $V_B = 12\text{ V}$ ;  $T_{mb} = 30\text{ °C}$ ;  $Z_S = Z_L = 75\ \Omega$ .

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$G_p$	power gain	$f = 10\text{ MHz}$	25	26	dB
SL	slope straight line	$f = 5\text{ to }65\text{ MHz}$	-0.1	+0.6	dB
FL	flatness of frequency response	$f = 5\text{ to }65\text{ MHz}$	-	$\pm 0.2$	dB
$S_{11}$	input return losses	$f = 5\text{ to }65\text{ MHz}$	20	-	dB
$S_{22}$	output return losses	$f = 5\text{ to }65\text{ MHz}$	20	-	dB
CTB	composite triple beat	4 channels flat; $V_o = 50\text{ dBmV}$ ; measured at 25 MHz	-	-64	dB
$X_{mod}$	cross modulation	4 channels flat; $V_o = 50\text{ dBmV}$ ; measured at 25 MHz	-	-54	dB
$d_2$	second order distortion	note 1	-	-70	dB
NF	noise figure	$f = 65\text{ MHz}$	-	3.5	dB
$I_{tot}$	total current consumption	note 2	75	95	mA

**Notes**

- $f_p = 19\text{ MHz}$ ;  $V_p = 50\text{ dBmV}$ ;  $f_q = 31\text{ MHz}$ ;  $V_q = 50\text{ dBmV}$ ; measured at  $f_p + f_q = 50\text{ MHz}$ .
- The module normally operates at  $V_B = 12\text{ V}$ , but is able to withstand supply transients up to 30 V.

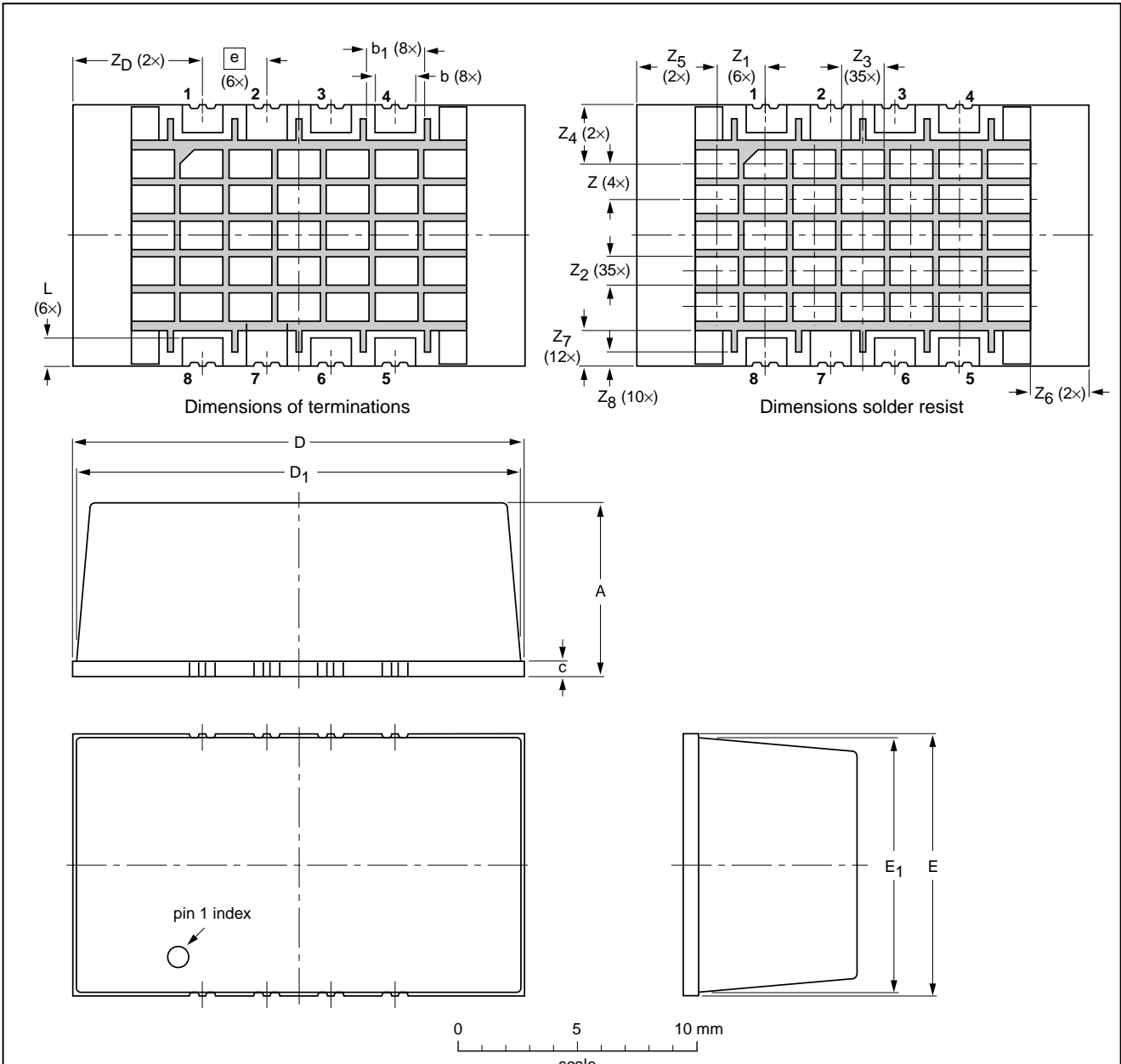
65 MHz, 25.5 dB gain reverse amplifier

BGS67A

PACKAGE OUTLINE

Leadless surface mounted package; plastic cap; 8 terminations

SOT567A



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	c	D	D <sub>1</sub>	E	E <sub>1</sub>	e	L	Z	Z <sub>1</sub>	Z <sub>2</sub>	Z <sub>3</sub>	Z <sub>4</sub>	Z <sub>5</sub>	Z <sub>6</sub>	Z <sub>7</sub>	Z <sub>8</sub>	Z <sub>D</sub>
mm	7.6	1.8	2.55	0.71	19.3	18.85	11.3	10.85	2.7	1.3	1.6	2.15	1.3	1.9	2.6	3.45	2.55	1.6	0.7	5.55
	7.1	1.6	2.35	0.57	18.7	18.55	10.7	10.55			1.4	1.95	1.1	1.7	2.4	3.25	2.35	1.4	0.5	5.35

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT567A						02-02-28 02-06-06

## 65 MHz, 25.5 dB gain reverse amplifier

BGS67A

## DATA SHEET STATUS

DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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This product is supplied in anti-static packing to prevent damage caused by electrostatic discharge during transport and handling. For further information, refer to Philips specs.: SNW-EQ-608, SNW-FQ-302A and SNW-FQ-302B.

65 MHz, 25.5 dB gain reverse amplifier

BGS67A

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**NOTES**

65 MHz, 25.5 dB gain reverse amplifier

BGS67A

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**NOTES**

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